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Contact us

Lead-free Green

AP7175

3A ULTRA LOW DROPOUT LINEAR REGULATOR WITH ENABLE

Description

The AP7175 is a 3.0A ultra low-dropout (LDO) linear regulator that features an enable input and a power-good output.

The enable input and power-good output allow users to configure power management solutions that can meet the sequencing requirements of FPGAs, DSPs, and other applications with different start-up and power-down requirements.

The AP7175 features two supply inputs, for power conversion supply and control. With the separation of the control and the power input very low dropout voltages can be reached and power dissipation is reduced.

A precision reference and feedback control deliver 1.5% accuracy over load, line, and operating temperature ranges.
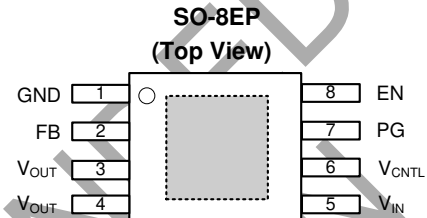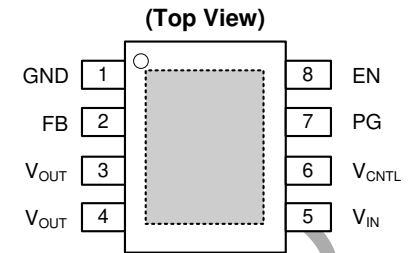
The AP7175 is available in SO-8EP and MSOP-8EP package with an exposed PAD to reduce the junction to case resistance and extend the temperature range it can be used in.

Pin Assignments

(Top View)

GND	1	8 EN
FB	2	7 PG
V_{OUT}	3	6 V_{CNTL}
V_{OUT}	4	5 V_{IN}

SO-8EP

(Top View)

GND	1	8 EN
FB	2	7 PG
V_{OUT}	3	6 V_{CNTL}
V_{OUT}	4	5 V_{IN}

MSOP-8EP

= PAD (connected to V_{IN})

Features

- V_{IN} Range: 1.2V to 3.65V V_{CNTL} 3.0V to 5.5V
- Adjustable output voltage
- Continuous Output Current I_{OUT} = 3A
- Fast transient response
- Power on reset monitoring on V_{CNTL} and V_{IN}
- Internal Softstart
- Stable with Low ESR MLCC Capacitors
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Applications

- Notebook
- PC
- Netbook
- Wireless Communication
- Server
- Motherboard
- Dongle
- Front Side Bus VTT (1.2V/3.3A)

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Typical Applications Circuit
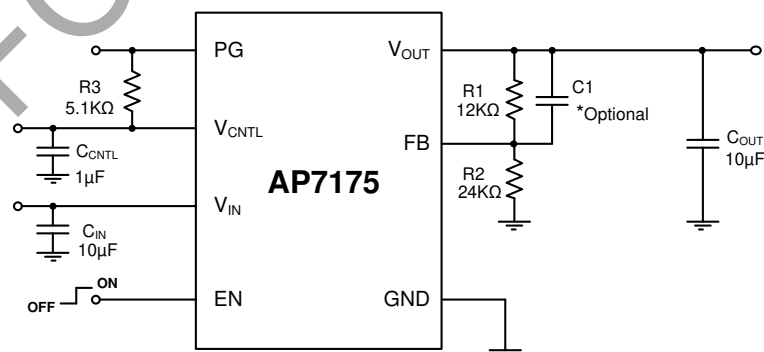
Figure 1. Typical Application Circuit

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Pin Descriptions

Pin Name	Pin Number		Function
	SO-8EP	MSOP-8EP	
GND	1	1	Ground
FB	2	2	Feedback to set the output voltage via an external resistor divider between V_{OUT} and GND.
V_{OUT}	3/4	3/4	Power Output Pin. Connect at least 10μF capacitor to this pin to improve transient response and required for stability. When the part is disabled the output is discharged via an internal pull-low MOSFET.
V_{IN}	5	5	Power Input Pin for current supply. Connect a decoupling capacitor (≥10μF) as close as possible to the pin for noise filtering.
V_{CNTL}	6	6	BIAS supply for the controller, recommended 5V. Connect a decoupling capacitor (≥1μF) as close as possible to the pin for noise filtering.
PG	7	7	Power Good output open drain to indicate the status of V_{OUT} via monitoring the FB pin. This pin is pulled low when the voltage is outside the limits, during thermal shutdown and if either V_{CNTL} or V_{IN} go below their thresholds.
EN	8	8	Enable pin. Driving this pin low will disable the part. When left floating an internal current source will pull this pin high and enable it.
PAD	EP	EP	Exposed pad connect this to V_{IN} for good thermal conductivity.

Functional Block Diagram

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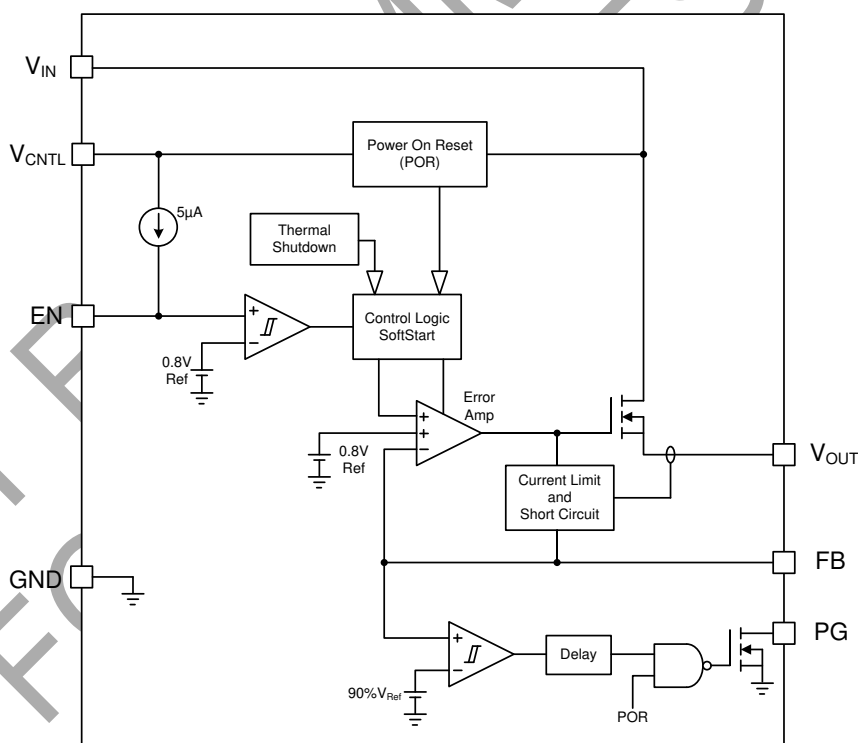
Absolute Maximum Ratings (Note 4) (@T$_A$ = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
V$_{IN}$	V$_{IN}$ Supply Voltage (V$_{IN}$ to GND)	-0.3 to +4.0	V
V$_{CNTL}$	V$_{CNTL}$ Supply Voltage (V$_{CNTL}$ to GND)	-0.3 to +7.0	V
V$_{OUT}$	V$_{OUT}$ to GND Voltage	-0.3 to V$_{IN}$ +0.3	V
—	PG to GND Voltage	-0.3 to +7.0	V
—	EN, FB to GND Voltage	-0.3 to V$_{CNTL}$ +0.3	V
P$_D$	Power Dissipation (SO-8EP)	1.7	W
	Power Dissipation (MSOP-8EP)	1.5	W
T$_J$	Maximum Junction Temperature	+150	°C
T$_{STG}$	Storage Temperature	-65 to +150	°C
T$_{SDR}$	Maximum Lead Soldering Temperature, 10 Seconds	+260	°C

Note: 4. Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

Recommended Operating Conditions (@T$_A$ = +25°C, unless otherwise specified.)

Symbol	Parameter		Min	Max	Unit
V$_{CNTL}$	V$_{CNTL}$ Supply Voltage		3.0	5.5	V
V$_{IN}$	V$_{IN}$ Supply Voltage		1.2	3.65	V
V$_{OUT}$	V$_{OUT}$ Output Voltage (when V$_{CNTL}$-V$_{OUT}$ >1.9V)		0.8	V$_{IN}$ - V$_{DROP}$	V
I$_{OUT}$	V$_{OUT}$ Output Current	Continuous Current	0	3	A
		Peak Current	0	4	
C$_{OUT}$	V$_{OUT}$ Output Capacitance	I$_{OUT}$ = 3A at 25% nominal V$_{OUT}$	8	1100	µF
		I$_{OUT}$ = 2A at 25% nominal V$_{OUT}$	8	1700	
		I$_{OUT}$ = 1A at 25% nominal V$_{OUT}$	8	2400	
E$_{SRCOUT}$	ESR of V$_{OUT}$ Output Capacitor		0	200	mΩ
T$_A$	Ambient Temperature		-40	+85	°C
T$_J$	Junction Temperature		-40	+125	°C

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Electrical Characteristics

(V_{CNTL} = 5V, V_{IN} = 1.8V, V_{OUT} = 1.2V and T_A = -40 to +85°C, @T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions		AP7175			Unit
				Min	Typ	Max	
SUPPLY CURRENT							
IV$_{CNTL}$	V_{CNTL} Supply Current	EN = V_{CNTL}, I_{OUT}=0A		—	1.0	1.5	mA
I$_{SD}$	V_{CNTL} Supply Current at Shutdown	EN = GND		—	15	30	µA
—	V_{IN} Supply Current at Shutdown	EN = GND, V_{IN}=3.65V		—	—	1	µA
POWER-ON-RESET (POR)							
—	Rising V_{CNTL} POR Threshold	—		2.5	2.7	2.95	V
—	V_{CNTL} POR Hysteresis	—		—	0.4	—	V
—	Rising V_{IN} POR Threshold	—		0.8	0.9	1.0	V
—	V_{IN} POR Hysteresis	—		—	0.5	—	V
OUTPUT VOLTAGE							
V$_{REF}$	Reference Voltage	FB = V_{OUT}		—	0.8	—	V
	Output Voltage Accuracy	V_{CNTL} =3.0 V to 5.5V, I_{OUT} = 0 to 3A, T_J = -40 to +125°C		-1.5	—	+1.5	%
	Load Regulation	I_{OUT} =0A to 3A		—	0.06	0.25	%
	Line Regulation	I_{OUT} =10mA, V_{CNTL} = 3.0 to 5.5V		-0.15	—	+0.15	%/V
	V_{OUT} Pull-low Resistance	V_{CNTL} = 3.3V, V_{EN} = 0V, V_{OUT} < 0.8V		—	10	—	Ω
	FB Input Current	V_{FB} = 0.8V		-100	—	100	nA
DROPOUT VOLTAGE							
V$_{DROP}$	V_{IN}-to-V_{OUT} Dropout Voltage (Note 5)	V_{CNTL} = 5.0V, I_{OUT} = 3A	V_{OUT} = 2.5V	T_J = +25°C	—	0.26	0.31	V
				T_J = -40 to +125°C	—	—	0.42	
			V_{OUT} = 1.8V	T_J = +25°C	—	0.24	0.29	
				T_J = -40 to +125°C	—	—	0.40	
			V_{OUT} = 1.2V	T_J = +25°C	—	0.23	0.28	
				T_J = -40 to +125°C	—	—	0.38	
I$_{LIM}$	Current-Limit Level	T_J = +25°C, V_{OUT} = 80% $V_{NOMINAL}$		4.5	5.7	6.7	A
		T_J = -40 to +125°C		4.2	—	—	A
PROTECTIONS							
I$_{SHORT}$	Short Current-Limit Level	V_{FB} < 0.2V		—	1.1	—	A
T$_{SD}$	Thermal Shutdown Temperature	T_J rising		—	+170	—	°C
—	Thermal Shutdown Hysteresis	—		—	+50	—	°C
ENABLE AND SOFT-START							
—	EN Logic High Threshold Voltage	V_{EN} rising		0.5	0.8	1.1	V
—	EN Hysteresis	—		—	0.1	—	V
—	EN Pull-High Current	EN = GND		—	5	—	µA
t$_{SS}$	Soft-Start Interval	—		0.3	0.6	1.2	ms
—	Turn On Delay	From being enabled to V_{OUT} rising 10%		200	350	500	µs
POWER-GOOD AND DELAY							
V$_{THPG}$	Rising PG Threshold Voltage	V_{FB} rising		90	92	95	%
—	PG Threshold Hysteresis	—		—	8	—	%
—	PG Pull-low Voltage	PG sinks 5mA		—	0.25	0.4	V
—	PG Debounce Interval	V_{FB} < falling PG voltage threshold		—	10	—	µs
—	PG Delay Time	From V_{FB} = V_{THPG} to rising edge of the V_{PG}		1	2	4	ms

Note: 5. Dropout voltage is the voltage difference between the inut and the output at which the output voltage drops 2% below its nominal value.
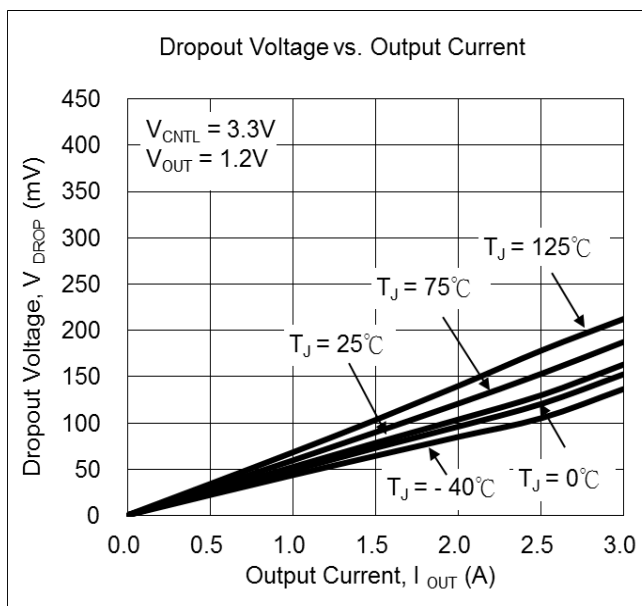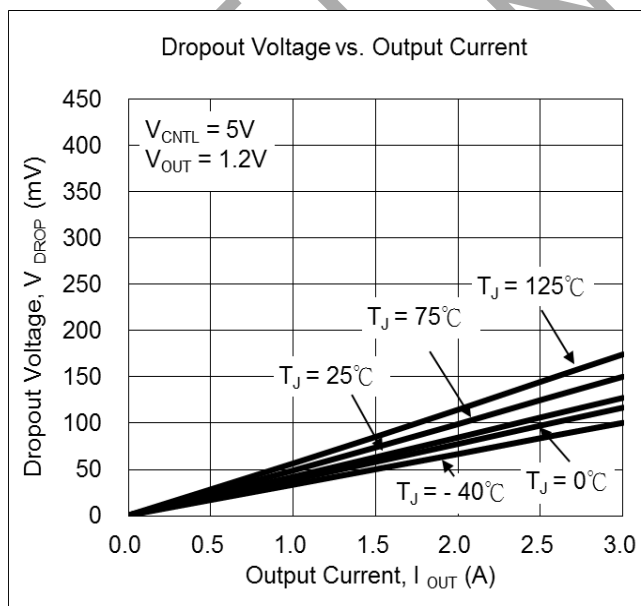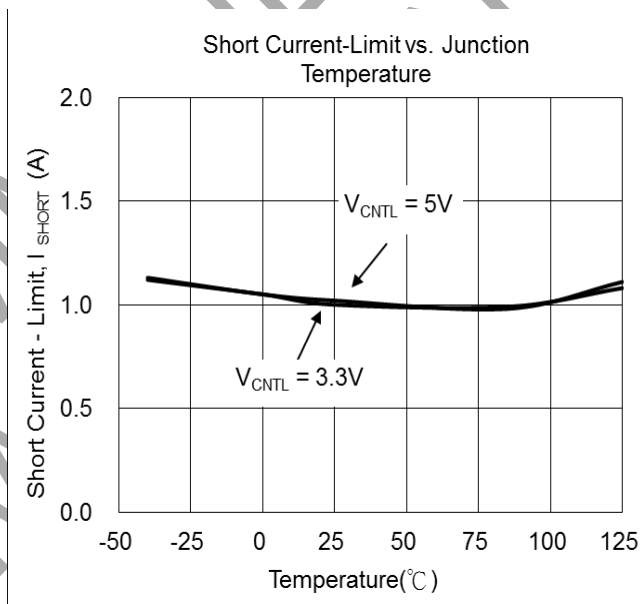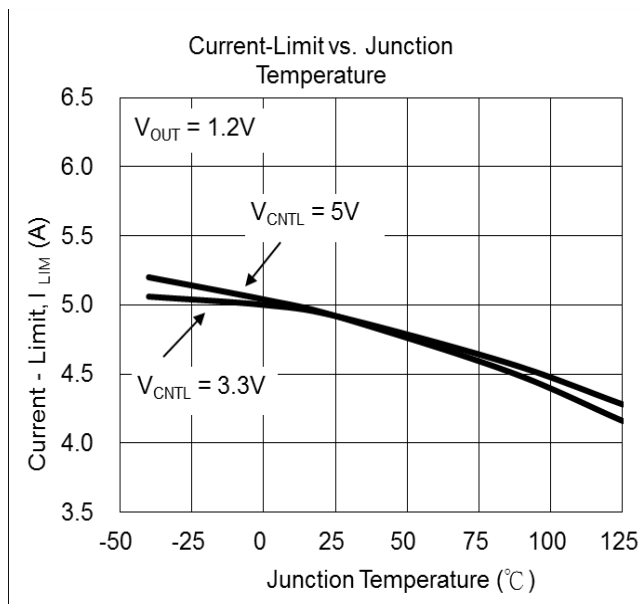
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Electrical Characteristics (Cont.)

(V_{CNTL} = 5V, V_{IN} = 1.8V, V_{OUT} = 1.2V and T_A = -40 to +85°C, @T_A = +25°C, unless otherwise specified.)
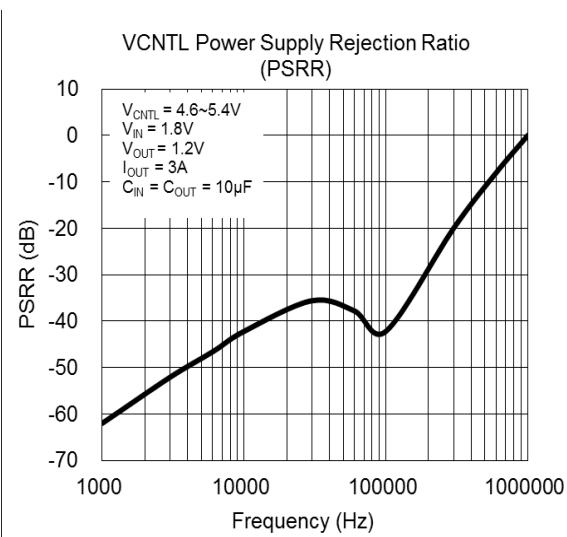
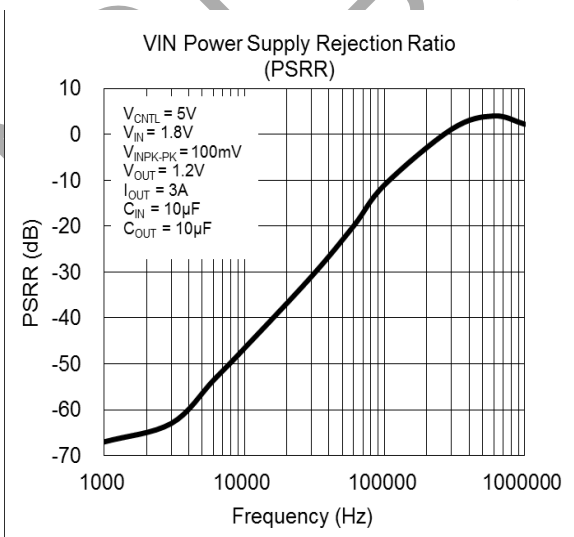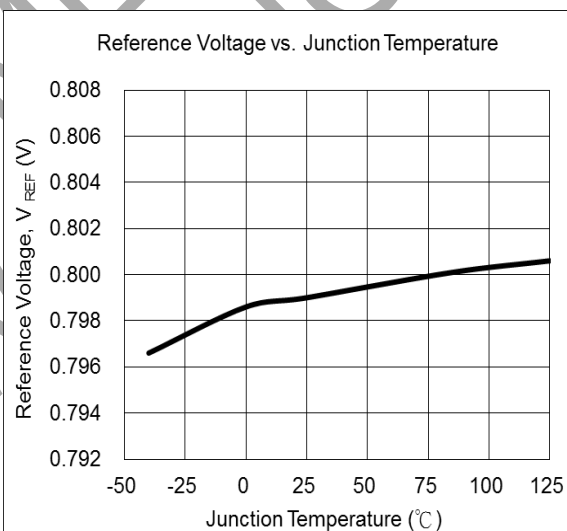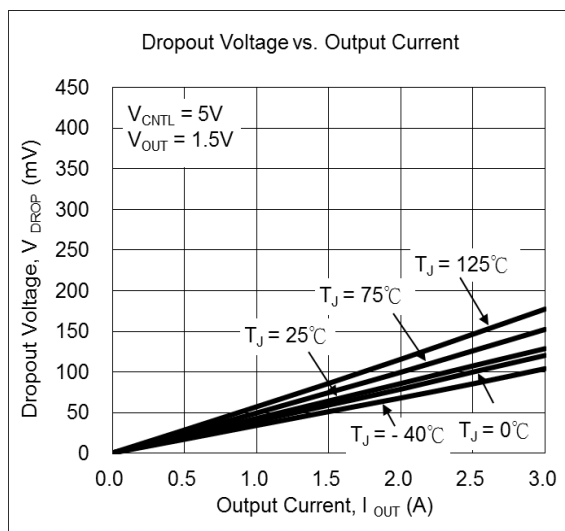| Symbol	Parameter	Test Conditions	AP7175			Unit
			Min	Typ	Max	
THERMAL CHARACTERISTIC						
θ_{JA}	Thermal Resistance Junction-to-Ambient	SO-8EP (Note 6)	—	70	—	°C/W
		MSOP-8EP (Note 7)	—	80	—	°C/W
θ_{JC}	Thermal Resistance Junction-to-Case	SO-8EP (Note 6)	—	30	—	°C/W
		MSOP-8EP (Note 7)	—	30	—	°C/W

Notes: 6. Device mounted on 2"*2" FR-4 substrate PC board, 2oz copper, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.
7. Device mounted on 2"*2" FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Typical Characteristics

Current-Limit vs. Junction Temperature


Short Current-Limit vs. Junction Temperature

Dropout Voltage vs. Output Current

Dropout Voltage vs. Output Current

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Typical Characteristics (Cont.)

Dropout Voltage vs. Output Current
$V_{CNTL} = 5V$, $V_{OUT} = 1.8V$

Dropout Voltage vs. Output Current
$V_{CNTL} = 5V$, $V_{OUT} = 2.5V$

Dropout Voltage vs. Output Current
$V_{CNTL} = 5V$, $V_{OUT} = 1.5V$

Reference Voltage vs. Junction Temperature

VIN Power Supply Rejection Ratio (PSRR)
$V_{CNTL} = 5V$
$V_{IN} = 1.8V$
$V_{INPK-PK} = 100mV$
$V_{OUT} = 1.2V$
$I_{OUT} = 3A$
$C_{IN} = 10\mu F$
$C_{OUT} = 10\mu F$

VCNTL Power Supply Rejection Ratio (PSRR)
$V_{CNTL} = 4.6\sim5.4V$
$V_{IN} = 1.8V$
$V_{OUT} = 1.2V$
$I_{OUT} = 3A$
$C_{IN} = C_{OUT} = 10\mu F$

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Operating Waveforms (@ V_{CNTL} = 5V, V_{IN} = 1.8V, V_{OUT} = 1.2V, T_A = +25°C, unless otherwise specified.)

Power On
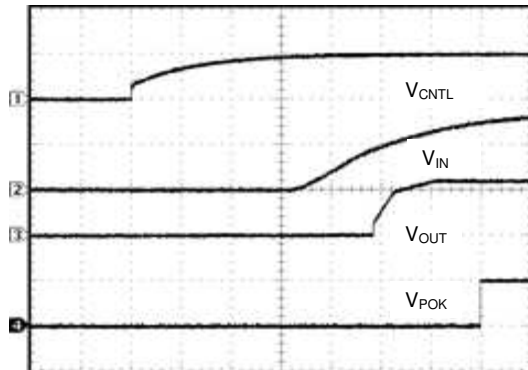
C_{OUT}=10µF, C_{IN}=10µF, R_L=0.4Ω
CH1: V_{CNTL}, 5V/Div, DC
CH2: V_{IN}, 1V/Div, DC
CH3: V_{OUT}, 1V/Div, DC
CH4: V_{POK}, 5V/Div, DC
TIME: 2ms/Div

Power Off
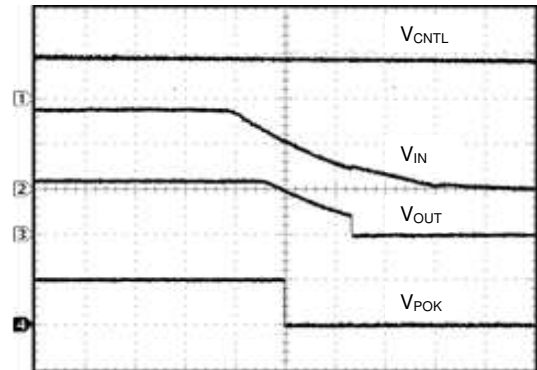
C_{OUT}=10µF, C_{IN}=10µF, R_L=0.4Ω
CH1: V_{CNTL}, 5V/Div, DC
CH2: V_{IN}, 1V/Div, DC
CH3: V_{OUT}, 1V/Div, DC
CH4: V_{POK}, 5V/Div, DC
TIME: 2ms/Div

Load Transient Response
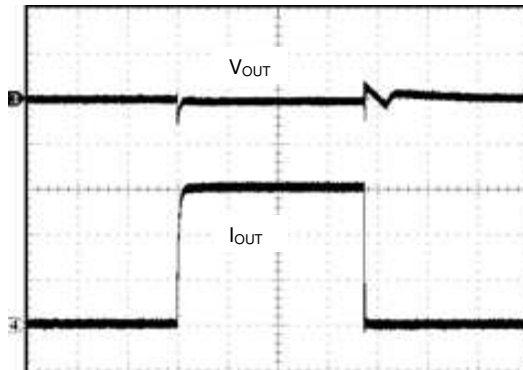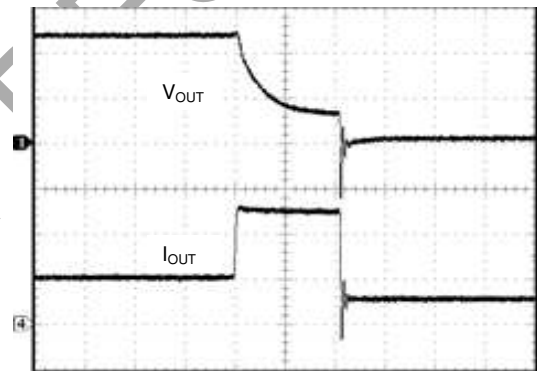

I_{OUT} = 10mA to 3A to10mA (rise / fall time =1µs)
C_{OUT} = 10µF, C_{IN} = 10µF
CH1: V_{OUT}, 50mV/Div, AC
CH2: I_{OUT}, 1A/Div, DC
TIME: 50µs/Div

Over Current Protection

C_{OUT} = 10µF, C_{IN} = 10µF, I_{OUT} = 2A to 5.6A
CH1: V_{OUT}, 0.5V/Div, DC
CH2: I_{OUT}, 2A/Div, DC
TIME: 0.2ms/Div

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Operating Waveforms (Cont.) (@ V_{CNTL} = 5V, V_{IN} = 1.8V, V_{OUT} = 1.2V, T_A = +25°C, unless otherwise specified.)

Shutdown
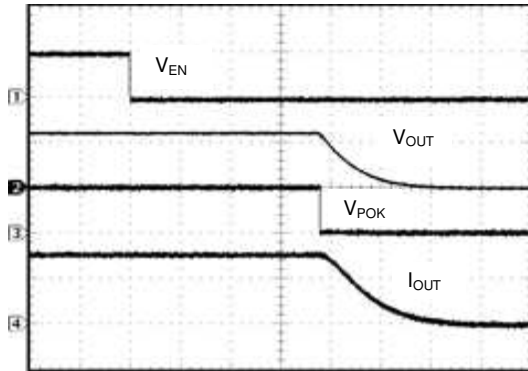
C_{OUT} = 10µF, C_{IN} = 10µF, R_L = 0.4Ω
CH1: V_{EN}, 5V/Div, DC
CH2: V_{OUT}, 1V/Div, DC
CH3: V_{POK}, 5V/Div, DC
CH4: I_{OUT}, 2A/Div, DC
TIME: 4µs/Div
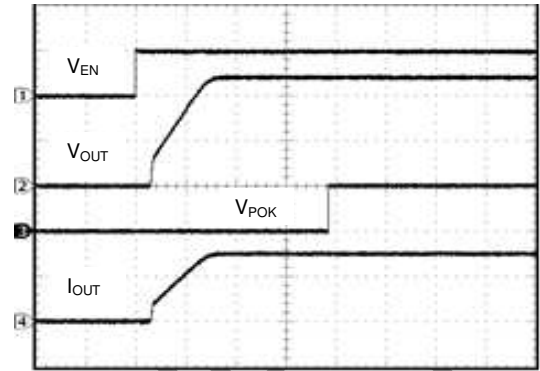
Enable

C_{OUT} = 10µF, C_{IN} = 10µF, R_L = 0.4Ω
CH1: V_{EN}, 5V/Div, DC
CH2: V_{OUT}, 1V/Div, DC
CH3: V_{POK}, 5V/Div, DC
CH4: I_{OUT}, 2A/Div, DC
TIME: 1ms/Div

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Application Information

Power Good and Delay

AP7175 monitors the feedback voltage V_{FB} on the FB pin. An internal delay timer is started after the PG voltage threshold (V_{THPG}) on the FB pin is reached. At the end of the delay time an internal NMOS of the PG is turned off to indicate that the power at the output is good (PG). This monitoring function is continued during operation and if V_{FB} falls 8% (typ) below V_{THPG}, the NMOS of the PG is turned on after a delay time of typical 10µs to avoid oscillating of the PG signal.

Power On Reset

AP7175 monitors both supply voltages, V_{CNTL} and V_{IN} to ensure operation as intended. A Soft-Start process is initiated after both voltages exceed their POR threshold during power on. During operation the POR component continues to monitor the supply voltage and pulls the PG low to indicate an out of regulation supply. This function will engage without regard to the status of the output.

Soft-Start

AP7175 incorporates an internal Soft-Start function. The output voltage rise is controlled to limit the current surge during start-up. The typical Soft-Start time is 0.6ms.

Current-Limit Protection

AP7175 monitors the current flow through the NMOS and limits the maximum current to avoid damage to the load and AP7175 during overload conditions.

Short Circuit Current-Limit Protection

AP7175 incorporates a current limit function to reduce the maximum current to 1.1A (typ) when the voltage at FB falls below 0.2V (typ) during an overload or short circuit situation.

During start-up period, this function is disabled to ensure successful heavy load start-up.

Enable Control

If the enable pin (EN) is left open, an internal current source of ~5µA pulls the pin up and enables the AP7175. This will reduce the bill of material saving an external pull up resistor. Driving the enable pin low disables the device. Driving the pin high subsequently initiates a new Soft-Start cycle.

Output Voltage Regulation

Output Voltage is set by resistor divider from V_{OUT} via FB pin to GND. Internally V_{FB} is compared to a 0.8V temperature compensated reference voltage and the NMOS pass element regulates the output voltage while delivering current from V_{IN} to V_{OUT}.

Setting the Output Voltage

A resistor divider connected to FB pin programs the output voltage.

$$V_{OUT} = V_{REF} * \left(1 + \frac{R1}{R2}\right) V$$

R1 is connected from V_{OUT} to FB with Kelvin sensing connection. R2 is connected from FB to GND. To improve load transient response and stability, a bypass capacitor can be connected in parallel with R1. (optional in typical application circuit)

Power Sequencing

AP7175 requires no specific sequencing between V_{IN} and V_{CNTL}. However, care should be taken to avoid forcing V_{OUT} for prolonged time without the presence of V_{IN}. Conduction through internal parasitic diode (from V_{OUT} to V_{IN}) could damage AP7175.

Thermal Shutdown

The PCB layout and power requirements for AP7175 under normal operation condition should allow enough cooling to restrict the junction temperature to +125°C. The packages for AP7175 have an exposed PAD to support this. These packages provide better connection to the PCB and thermal performance. Refer to the layout considerations.

If AP7175 junction temperature reaches +170°C a thermal protection block disables the NMOS pass element and lets the part cool down. After its junction temperature drops by 50°C (typ), a new Soft-Start cycle will be initiated. A new thermal protection will start, if the load or ambient conditions continue to raise the junction temperature to +170°C. This cycle will repeat until normal operation temperature is maintained again.

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Application Information (Cont.)

Output Capacitor

An output capacitor (C_{OUT}) is needed to improve transient response and maintain stability. The ESR (equivalent series resistance) and capacitance drives the selection. Care needs to be taken to cover the entire operating temperature range.

The output capacitor can be an Ultra-Low-ESR ceramic chip capacitor or a low ESR bulk capacitor like a solid tantalum, POSCap or aluminum electrolytic capacitor.

C_{OUT} is used to improve the output stability and reduces the changes of the output voltage during load transitions. The slew rate of the current sensed via the FB pin in AP7175 is reduced. If the application has large load variations, it is recommended to utilize low-ESR bulk capacitors.

It is recommended to place ceramic capacitors as close as possible to the load and the ground pin and care should be taken to reduce the impedance in the layout.

Input Capacitor

To prevent the input voltage from dropping during load steps it is recommended to utilize an input capacitor (C_{IN}). As with the output capacitor the following are acceptable, Ultra-Low-ESR ceramic chip capacitor or low ESR bulk capacitor like a solid tantalum, POSCap or aluminum electrolytic capacitor. Typically it is recommended to utilize an capacitance of at least 10µF to avoid output voltage drop due to reduced input voltage. The value can be lower if V_{IN} changes are not critical for the application.

Layout Considerations

For good ground loop and stability, the input and output capacitors should be located close to the input, output, and ground pins of the device. No other application circuit is connected within the loop. Avoid using vias within ground loop. If vias must be used, multiple vias should be used to reduce via inductance.

The regulator ground pin should be connected to the external circuit ground to reduce voltage drop caused by trace impedance. Ground plane is generally used to reduce trace impedance.

Wide trace should be used for large current paths from V_{IN} to V_{OUT}, and load circuit.

Place the R1, R2, and C1 (optional) near the LDO as close as possible to avoid noise coupling.

R2 is placed close to device ground. Connect the ground of the R2 to the GND pin by using a dedicated trace.

Connect the pin of the R1 directly to the load for Kelvin sensing.

No high current should flow through the ground trace of feedback loop and affect reference voltage stability.

For the packages with exposed pads, heat sinking is accomplished using the heat spreading capability of the PCB and its copper traces. Suitable PCB area on the top layer and thermal vias(0.3mm drill size with 1mm spacing, 4~8 vias at least) to the Vin power plane can help to reduce device temperature greatly.

Reference Layout Plots

Top Layer

Bottom Layer

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Ordering Information

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Package
SP : SO-8EP
MP : MSOP-8EP

Packing
13 : Tape & Reel
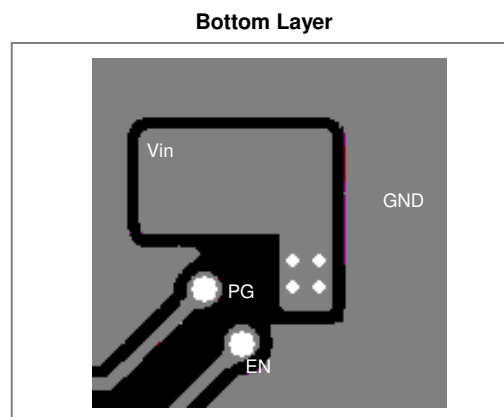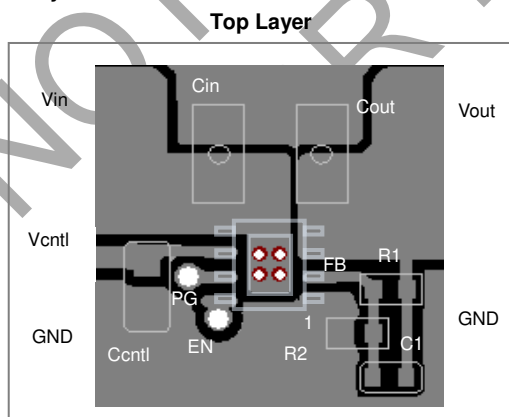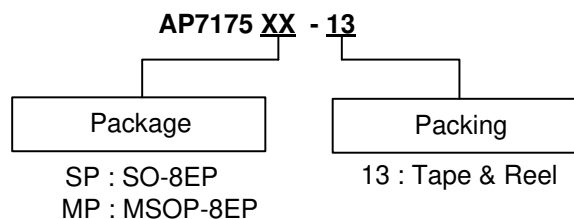
Part Number	Package Code	Packaging	13" Tape and Reel	
			Quantity	Part Number Suffix
AP7175SP-13	SP	SO-8EP	2500/Tape & Reel	-13
AP7175MP-13	MP	MSOP-8EP	2500/Tape & Reel	-13

Marking Information

(1)   SO-8EP

(Top View)

Logo

Part No

AP7175

YYWWXXE

YY : Year : 08, 09,10~
WW : Week : 01~52; 52 represents 52 and 53 week
X : Internal Code
SO-8EP
G : Green

(2)   MSOP-8EP

(Top View)

Logo

Part Number

AP7175

YWXE

A~Z : Internal Code
MSOP-8EP
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents 52 and 53 week

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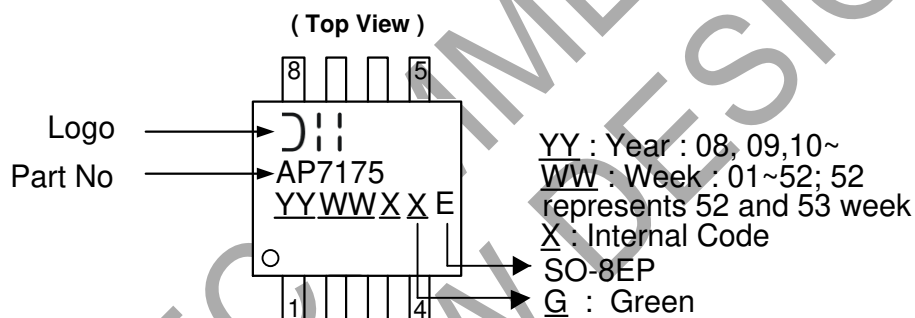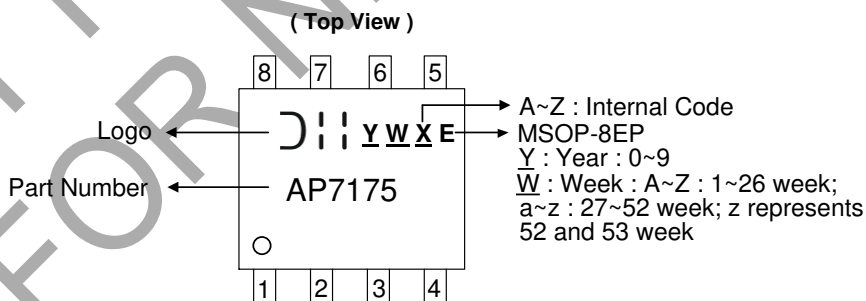
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) SO-8EP

SO-8EP			
Dim	**Min**	**Max**	**Typ**
A	1.40	1.50	1.45
A1	0.00	0.13	-
b	0.30	0.50	0.40
C	0.15	0.25	0.20
D	4.85	4.95	4.90
E	3.80	3.90	3.85
E0	3.85	3.95	3.90
E1	5.90	6.10	6.00
e	-	-	1.27
F	2.75	3.35	3.05
H	2.11	2.71	2.41
L	0.62	0.82	0.72
N	-	-	0.35
Q	0.60	0.70	0.65
All Dimensions in mm			

(2) MSOP-8EP

Detail C

MSOP-8EP			
Dim	**Min**	**Max**	**Typ**
A	-	1.10	-
A1	0.05	0.15	0.10
A2	0.75	0.95	0.86
A3	0.29	0.49	0.39
b	0.22	0.38	0.30
c	0.08	0.23	0.15
D	2.90	3.10	3.00
D1	1.60	2.00	1.80
E	4.70	5.10	4.90
E1	2.90	3.10	3.00
E2	1.30	1.70	1.50
E3	2.85	3.05	2.95
e	-	-	0.65
L	0.40	0.80	0.60
a	0°	8°	4°
x	-	-	0.750
y	-	-	0.750
All Dimensions in mm			

See Detail C

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Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1)   SO-8EP
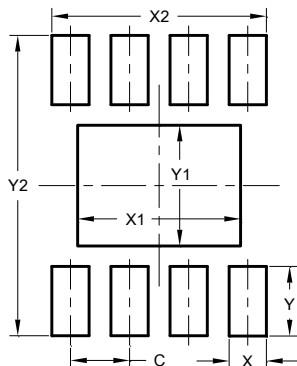
Dimensions	Value (in mm)
C	1.270
X	0.802
X1	3.502
X2	4.612
Y	1.505
Y1	2.613
Y2	6.500

(2)   MSOP-8EP
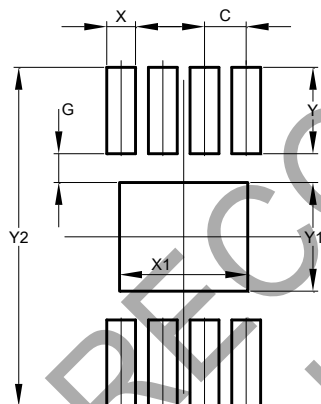
Dimensions	Value (in mm)
C	0.650
G	0.450
X	0.450
X1	2.000
Y	1.350
Y1	1.700
Y2	5.300

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